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Coupling Cortical Neurons through Electronic Memristive Synapse

Elvira Juzekaeva, Azat Nasretidinov, Silvia Battistoni, Tatiana Berzina, Salvatore Iannotta, Rustem Khazipov, Victor Erokhin,* and Marat Mukhtarov

Functional coupling live neurons through artificial synapses is the primary requirement for their implementation as prosthetic devices or in building hybrid networks. Here, the first evidence of unidirectional, activity dependent, coupling of two live neurons in brain slices via organic memristive devices (OMD) is demonstrated. OMD is a polymeric electrochemical element, which has two terminals for the connection in electrical circuits and which displays hysteresis and rectifying features. OMD coupling is characterized by nonlinear relationships determined by the instantaneous values of OMD resistance that can be controlled by the neuronal activity, and the excitation threshold in the postsynaptic neuron. OMD coupling also has the spike-timing features similar to that of the natural excitatory synapses. Also, OMD-synapses support synchronized delta-oscillations in the two-neuron network. It is proposed that OMD-synapses may enable realization of prosthetic synapses and building hybrid neuronal networks endowed with a capacity of learning, memory, and computation.

A synapse is a biological structure, which connects two neurons enabling specific and unidirectional information flow (excitation or inhibition) from one neuron to another. Synaptic connections are the key elements of the neuronal networks and their plasticity underlies learning and memory. Recent progress in building artificial neuronal networks is largely based on the elements mimicking features of natural synapses in silico or in electrico.^[1–3] Hybrid networks, in which brain-computer systems read and control the activity of live cells also require interphase devices with cellular resolution. Use

of electrophysiological spike-sorting^[4] and optogenetic^[5] approaches enables an efficient readout and control over activity of single or groups of neurons leading to a development of prosthetic devices. For example, fMRI-guided electrophysiological recordings of single motor cortex neurons involved in specific motor tasks combined with muscle electrostimulation enabled to produce prosthesis with a remarkable alleviation of the neurological deficits in hemiplegic patients with a traumatic lesion of synaptic connections between the corticospinal neurons and motor neurons in spinal cord.^[6] Restoration of synaptic connections as in the case of traumatic injury above as well as in other pathologies associated with a synaptic loss of function and various synaptopathies could be also solved through an introduction of electronic synapses to connect neurons

directly, given that these artificial synapses recapitulate the main feature of natural synapses including their plasticity. Moreover, development of electronic synapses with unprecedented, due to biological restraints, features during evolution could result in creation of cyborgs with unprecedented capacities.

We used patch-clamp recordings from nonconnected pairs of cortical layer 5 pyramidal neurons in rat brain slices (**Figure 1a**). Action potentials (APs) evoked by suprathreshold depolarizing current injection in either neuron failed to evoke any response in another cell in the pair (**Figure 1c**), indicating that these cells were not connected by natural synapses in either direction. These neurons were then connected through an electronic circuit with an OMD, playing the role of a synapse analog (**Figure 1b**). The structure of the OMD included a conducting polymer—polyaniline (PANI), with a solid electrolyte—lithium salt doped polyethylene oxide (PEO), and its memristive features were based on the high difference in PANI conductivity in the oxidized and reduced forms.^[7,8] The ratio of PANI conductivity in oxidized and reduced forms is in the order of 10^8 .^[8] However, the need to have a medium for these reactions reduces the maximum reported ratio for the entire device till about 10^5 .^[9] After setting the OMD resistance initially at high values by negative voltage loading (**Figure 1d**, bottom), APs in a “presynaptic” Cell 1 (**Figure 1d**, plot 2) were induced by a suprathreshold depolarizing steps (**Figure 1d**, plot 1). However, these APs in Cell 1 evoked only a subthreshold depolarizing response in the “postsynaptic” Cell 2 (**Figure 1d**, plot 4, the first

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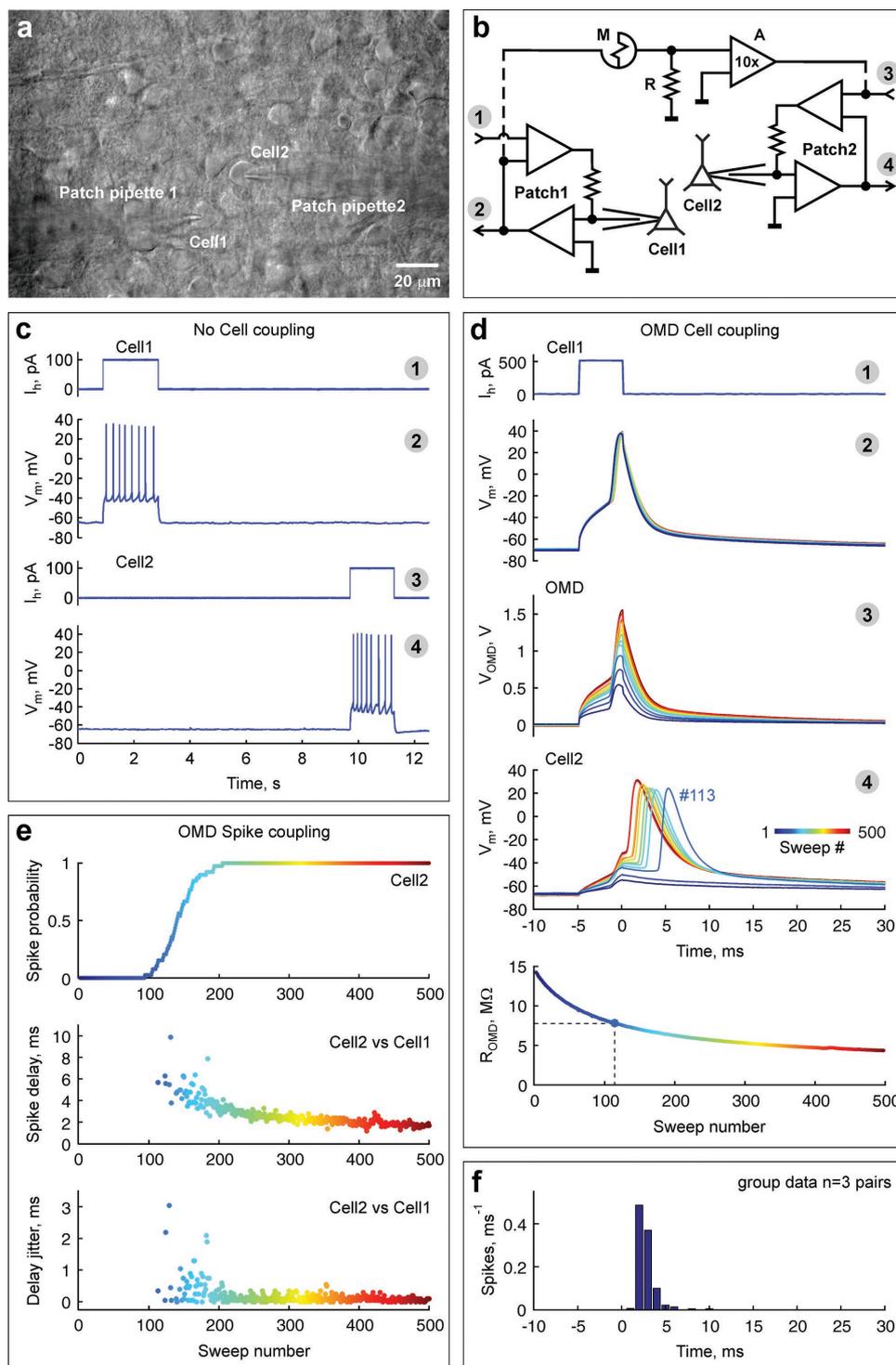


Figure 1. Activity-dependent coupling of neurons by OMD. a) Infrared differential interference contrast microphotograph of a P7 rat brain slice with visually identified L5/6 neocortical cells (Cell1,2) recorded simultaneously. b) Simplified electrical scheme of two patch-clamp amplifier headstages (Patch1,2): 1,3—patch-clamp holding inputs; 2,4—patch-clamp primary outputs; and an OMD-based circuit (5×5 mm) connecting two neurons. c,d) Traces of current-clamp recordings from Cells 1 and 2 before c) and after d) OMD-coupling. Traces 1–4 correspond to the inputs/outputs as labeled in b. Note that prior to OMD-coupling (c) APs in either neuron failed to evoke responses in the other neuron, indicating that these cells were not connected by natural synapses. After connection of Cells 1 and 2 through OMD (d), the efficacy of coupling progressively increases with each consecutive depolarizing step/AP in Cell1. 500 traces (color coded by sweep #) are aligned with suprathreshold depolarizing steps delivered to Cell1. Bottom plot, OMD resistance as a function of the sweep #. Dashed lines indicate the first sweep when Cell2 started firing. e) Corresponding plots of the activity-dependent change in spike probability in Cell2 (top), spike delay of Cell2 from Cell1 (middle) and spike delay jitter in Cell2 (bottom). f) Histogram of the spike delay in Cell2 from Cell1 calculated for three OMD-coupled cell pairs (777 spikes).

blue color coded sweeps) due to high initial OMD resistance (Figure 1d, bottom panel and 1e, top panel). Since the OMD resistance reduces upon depolarization,^[10] the consecutive depolarizing steps and the APs in Cell 1 induced a gradual increase in voltage responses from the OMD (Figure 1d, plot 3) and in Cell 2 (Figure 1d, plot 4). When the OMD resistance decreased by a factor ≈ 2 (Figure 1d, bottom, sweep #113), the depolarizing response in Cell2 reached the AP threshold (≈ -40 mV) and Cell 2 started reliably fire APs (Figure 1d, plot 4, sweep #113 onwards and Figure 1e). Along with a further decrease in OMD resistance (Figure 1d, bottom), the firing probability of Cell 2 gradually increased (Figure 1e, top). The activity-dependent increase in spike coupling between neurons was also associated with an improvement in the spike-timing through the OMD synapse as evidenced by a progressive reduction in the AP delays (Figure 1d, plot 4 and Figure 1e, middle plot), and a reduction in the jitter of AP delays (Figure 1d, plot 4 and Figure 1e, bottom plot).^[11,12] Figure 1f shows the histogram summarizing the delay times of Cell2 spiking from t Cell1 for three cell pairs (777 spikes recorded). It is noteworthy that the characteristic timing of the AP commutation through the OMD-synapse is similar to that of natural excitatory synapses.^[13]

To further assess the synaptic response, we also examined whether OMD coupling could enable neuronal synchronization during spontaneous activity. To this end, presynaptic Cell1 was continuously depolarized by injection of constant inward current to allow spontaneous firing (Figure 2a, blue trace). We observed that the firing of Cell1 induced a gradual decrease in OMD resistance (Figure 2d, bottom) which in turn induces an increase in Cell2 responses as in the experiments above (Figure 2a, red trace). As soon as the suprathreshold level of cell coupling was achieved, Cell2 started firing APs in synchrony with Cell 1 (Figure 2a,d), yet with a 3.8 ± 0.1 ms time lag ($n = 3$ cell pairs, 633 spikes recorded; Figure 2e). Synchronized firing of the OMD-coupled neurons occurred in the δ -frequency range (0.56 ± 0.04 Hz, $n = 3$ cell pairs; Figure 2b,c) that is characteristic of the slow-wave cortical activity during deep sleep.^[14]

In this study, we provide for the first time experimental evidence of the unidirectional, activity-dependent, coupling of live neurons through the organic memristive device (OMD). We demonstrate that the spike-timing features of the OMD-synapse approach those of the natural excitatory synapses, that the magnitude of OMD-coupling can be controlled by the neuronal activity, and that OMD synapses efficiently support neuronal synchronization, in a simple two-neuron network.

Electronic devices (organic and inorganic) have been used to record extracellular field changes,^[15] cellular action potential^[16–18] and in vivo electrophysiological recordings.^[19] Despite its large interest, the realization of prototype of artificial synapse chips is mostly focused on the controlled release of chemical compounds^[20] through micropatterned substrates^[21,22] more than on the creation of a functional interface between devices and cells. Such kind of connection must allow the signal transmission between cells and device and, most important, the transmission of stimulations between groups of cells through the device. There are several works, where silicon circuits were used for mimicking synapse functions.^[1,2] Recently, memristive devices^[23,24] have been used as electronic analogs of synapses.^[25,26] Several memristor-based circuits have demonstrated plasticity suitable

for artificial neural networks,^[27,28] mimicked the learning of simple animals,^[29,30] and been used for the acquisition and partial decoding of signals from retina.^[31] However, the evidence that memristors could functionally couple live neurons is still missing. This is the primary requirement for their implementation in prosthetic devices or in building hybrid networks that requires the use of special materials in adequate configurations. Furthermore, if we consider the perspective of implantable systems, one must fulfill requirements such as biocompatibility, flexibility, and stretchability. In this framework here, we demonstrate a quite novel functionality with the first evidence of unidirectional, activity-dependent coupling of two live neurons in brain slices via OMDs. OMD coupling is characterized by nonlinear relationships determined by the instantaneous resistance of OMD depending on the connected neuronal activity, and by the observed excitation threshold in the postsynaptic neuron. We demonstrate that the OMD coupling shows also spike-timing features similar to those typical of natural excitatory synapses. Furthermore our OMD-synapses efficiently support synchronized delta-oscillations in the two-neuron network. All such features, ever observed simultaneously in such a simple single device, make OMD-synapses eligible for a significant step toward the realization of prosthetic synapses.

For considering these devices as elements for synapse prosthesis some major important properties are required: 1) they must show plasticity in signal transmission emulating that typical in living beings; 2) for implants, devices must be flexible and made of biocompatible materials; 3) size of the elements must be comparable with cell dimensions; 4) interconnections and external electronics system should not significantly disturb the functioning of the nervous system. Each of these features requires appropriate studies and optimizations. For items 2) and 3), there are already positive solutions. In fact, since the early works it has been shown that OMD can be realized in a flexible configuration.^[9] As far as the biocompatibility of the materials for OMD is concerned, it has been demonstrated in experiments of growth of cells^[32,33] and simple organisms^[34–36] on their surface. Moreover, the active channel can be fabricated by the so-called layer-by-layer technique,^[37] allowing the formation of architectures, where all the parts in contact with the biological surrounding are made of biocompatible polymers.^[38,39] Requirement 3) has also been demonstrated, showing the scalability of the OMDs^[40] by fabricating devices with lateral sizes of $20 \mu\text{m}$ ^[41] that can be scaled further, as it was shown to be possible the realization of submicron organic electronic systems.^[42]

Thus, the major challenges concern properties 1) and 4) that requires further studies and developments. In particular, the question of interconnects and external electronics 4) is very critical in the case of brain implants, a subject of large efforts by several groups.^[1,2,43]

The aim of this work is to address and contribute to develop the major requirement 1) hence concentrating our efforts to demonstrating, for the first time directly, that OMDs can have the same plasticity of electrical properties of the chemical synapses in living beings.

The major outcome of this study is that we provide experimental evidence of unidirectional, activity-dependent coupling of live neurons through an organic memristive device. We demonstrate that the spike-timing features of the OMD-synapse are very similar down to several details to those of natural excitatory synapses, that the magnitude of OMD-coupling can be regulated by neuronal

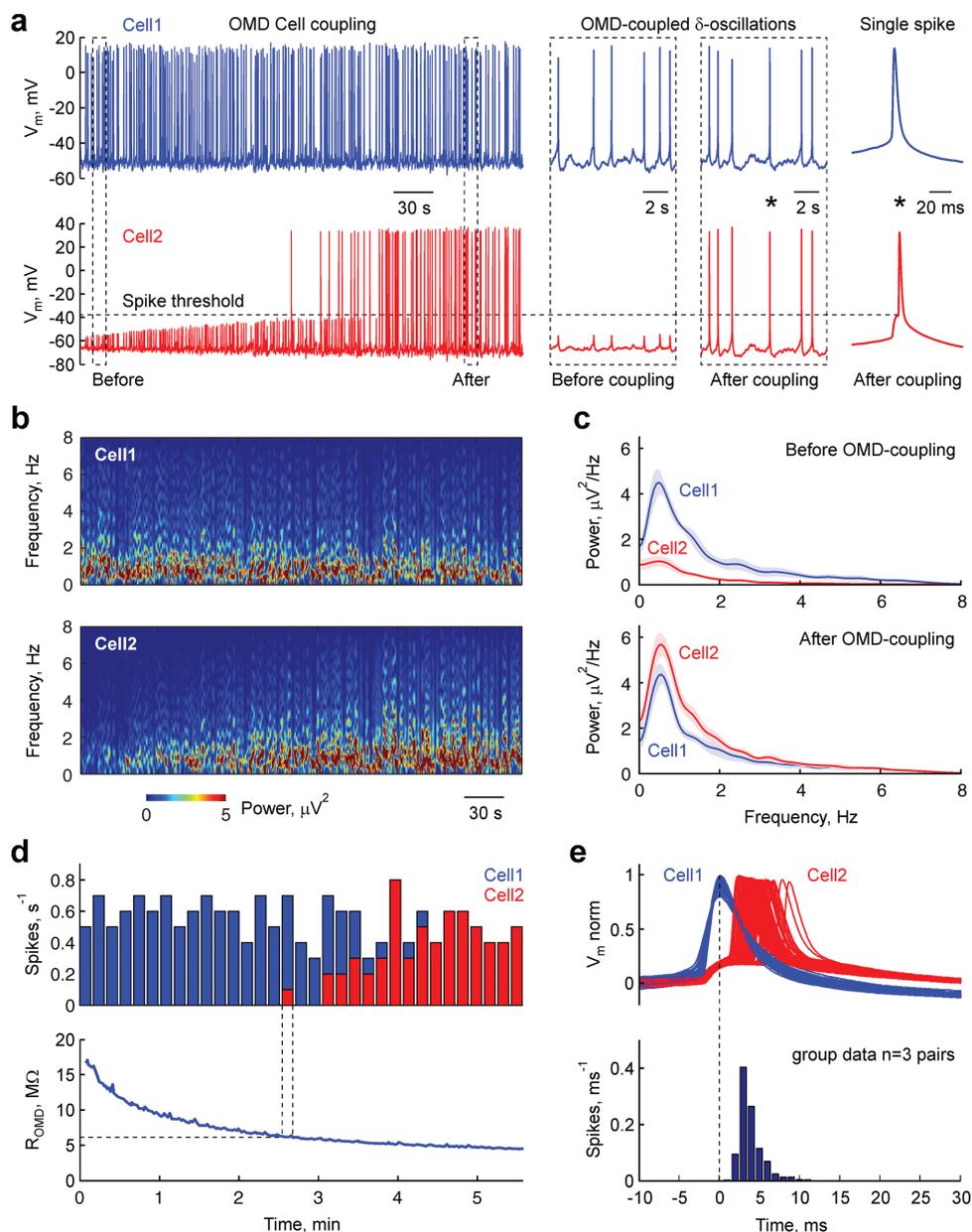


Figure 2. Synchronous oscillations in a two OMD-coupled neuron network. a) Current-clamp recordings from Cell1 (blue) and Cell2 (red). Parts of traces outlined by dashed boxes before and after spike coupling through OMD are shown on expanded time scales on the right. The horizontal dashed line indicates Cell2 spike threshold. b) Corresponding membrane potential spectrograms in Cells 1 and 2. c) Power spectrum density plots of the membrane potential in Cells 1 and 2 before (top) and after (bottom) spike-coupling through OMD (confidence interval is shadowed; $n = 3$ pairs). d) Frequency of spikes (top) in Cell1 (blue) and Cell2 (red) calculated for the 10 s bin intervals from the recordings shown in a and the corresponding values of OMD resistance (bottom). Dashed lines indicate the onset of spike-coupling between Cells 1 and 2. e) Example of 65 normalized spikes (top) recorded in Cell1 (blue traces) and Cell2 (red traces) and the histogram of the spike delay in Cell2 from Cell1 (bottom), data from three OMD-coupled cell pairs (633 spikes) are pooled together.

activity, and that OMD synapses efficiently support neuronal synchronization in a simple two-neuron network. We therefore give important indications that OMDs apart of being key candidate elements for neuromorphic computational systems (where up to now purely electronic elements have been used for information storage and processing^[10]), they also should be considered as suitable elements for developing “synapse prosthesis,” and useful for

neuromorphic computational systems, where the same elements will be used for memorizing and processing information.

Experimental Section

OMD Construction and Preparation: The schematic structure of the organic memristive device is shown in Figure S1a (Supporting

Information). Construction of the OMD followed the method already reported in several papers.^[44,45] A glass substrate with two evaporated separated chromium electrodes (Source and Drain) was masked with kapton tape to form a channel of about 5 × 15 mm to be exposed to the deposition. This metal was used because it provides a good adhesion to used supports (as contact areas are beyond zones where redox reactions occur, there is no requirement on the inert nature of the used metal). Then it was carefully washed with soap and sonicated in MilliQ water for 20 min before the deposition. The polyaniline conductive channel was deposited on this insulating support using the Langmuir–Schaefer technique in which monolayers of the chosen reagents are deposited on horizontally oriented substrates. Details of the used approach can be found in ref. [46]. It allows the deposition of films with a single layer resolution. It is very important regarding the working principle of the device: on the one hand it must provide reliable conductivity values (therefore, minimum thickness is 6–8 nm;^[10] on the other hand, it must be very thin for allowing fast exchange of Li⁺ ions between PANI and PEO. Therefore, 100 nm of the film thickness in this study was a good compromise for reaching the best device conditions. The preparation of polyaniline solution used has been reported in several papers^[7,10] and starts with the dissolution of the emeraldine base form of polyaniline (PANI-Sigma Aldrich $M_w \approx 10\,000$) in 1-methyl-2-pyrrolidinone (Sigma Aldrich ACS reagent $\geq 99.0\%$) reaching a concentration of 0.1 mg mL⁻¹ and with the addition of 10% of toluene (AnalaR NORMAPUR ACS). Once this solution was spread at the air/water interface with subphase (MilliQ water), it is cut in sections by a specially designed grid and finally deposited on the glass substrate. In all our devices, the conductive channel was formed by touching 60 times the interface and this corresponds to the deposition of 60 monolayers of PANI (≈ 100 nm). This polymeric channel undergoes to two doping processes to complete the protonation into its conductive form (emeraldine salt). The doping processes were performed by dipping the sample into HCl 1 M for 30 s and, after a resting time of 30–40 min, for 15 s. A water solution (20 mg mL⁻¹) of polyethylene oxide ($M_w = 8 \times 10^6$ Da (PEO)) doped with 0.1 M LiClO₄ (Sigma) was deposited the PANI active channel in a crossed configuration, inserting in it a reference electrode (Gate) made of a silver wire of 0.05 mm diameter. Finally the device was exposed to HCl vapors for few seconds before starting the characterizations. The device was covered with thin Kapton film to prevent dedoping and reactions with surrounding atmosphere.^[47]

OMD Electrical Connection and Properties: A scheme of the electrical circuit for the investigation of OMD properties is shown in Figure S1b (Supporting Information): 1—input; M—OMD; R—resistor (1 M Ω); A—instrumentation amplifier (AD620, Analog Devices, USA) with the gain set to $\times 10$; 2—output. Measurements were carried out in the environmental surrounding. When 1 ms pulses were applied to the input 1) pulses with progressively increased amplitude were taken from the output 2) depending the resistance of the OMD (Figure S1c, Supporting Information). Input pulses with amplitude of 0.2 V and intersweep interval of 100 ms were accompanied by a positive offset of 0.13 V to potentiate the OMD conductivity. Each recording of 1000 pulse sweeps was preceded by negative conditioning of -0.5 V applied to the input 1) for 100 s (1000 sweeps of 100 ms) to depress the OMD conductivity. When OMD was connected into the recording circuit in reverse, it demonstrated semiconductive properties (Figure S1d, Supporting Information) as a natural chemical synapses.

Brain Slice Preparation: All animal-use protocols followed the guidelines of the French National Institute of Health and Medical Research (INSERM, protocol N007.08.01) and the Kazan Federal University on the use of laboratory animals (ethical approval by the Institutional Animal Care and Use Committee of Kazan State Medical University N9-2013). Acute horizontal brain slices were prepared from postnatal day (P)7-15 Wistar rats of either sex. The animals were anesthetized with isoflurane (5%), decapitated, and the brain rapidly removed to oxygenated (95% O₂—5% CO₂) ice-cold (2–4 °C) artificial cerebrospinal fluid (ACSF) of the following composition (in $\times 10^{-3}$ M): NaCl 126, KCl 3.5, CaCl₂ 2, MgCl₂ 1.3, NaHCO₃ 25, NaH₂PO₄ 1.2 and glucose 11 (pH 7.4). Four hundred μ m thick horizontal slices were cut

using a PELCO easiSlicer vibratome (Ted Pella, Inc., Redding, CA, USA). Slices were kept in oxygenated ACSF at room temperature (20–22 °C) for at least 1 h before use. For recordings, slices were placed into a submerged chamber and superfused with oxygenated ACSF at 30–32 °C at a flow rate of 10 mL min⁻¹.

Electrophysiological Recordings: Whole-cell patch-clamp recordings were performed on visually identified L5/6 neocortical pyramidal cells using a BX51WI upright microscope equipped with a 40 \times /0.80 LUMPlanFL N objective (Olympus, Tokyo, Japan) and a QIClick-R-F-M-12 CCD camera (QImaging, Surrey, BC, Canada). Electrodes were pulled from borosilicate glass capillaries (BF150-86-10, Sutter Instrument, Novato, CA, USA) and had resistances of 4–7 M Ω . Pipette solution contained (in $\times 10^{-3}$ M): K-methanesulfonate 115; KCl 20; MgCl₂ 2; Na₂ATP 4; NaGTP 0.3; Hepes 10; buffered to pH 7.3 with KOH. Electrodes were connected via chloride silver wire to the headstages of a MultiClamp700B patch-clamp amplifier (Molecular Devices, Sunnyvale, CA, USA). Recordings were performed in current-clamp mode. The signals were digitized at 10 kHz using a Digidata 1440A analog-to-digital converter (Molecular Devices, Sunnyvale, CA, USA) and saved on a PC for post-hoc analysis using custom-written procedures in MATLAB (MathWorks, Inc., Natick, MA, USA).

OMD Connection to Living Cells: OMD is connected to living cells using the path-clamp amplifier and matching circuit shown in Figure S1b (Supporting Information). The signal from the primary output of the Cell1 clamped headstage (Patch1, Figure 1b) after $\times 20$ amplification was applied to OMD in AC mode accompanied by a positive offset of 0.13 V to potentiate device conductivity. The signal from OMD after $\times 10$ amplification (Figure S1b, Supporting Information) was applied to the command input of the Cell2 clamped headstage (Patch2, Figure 1b). Each recording was preceded by negative conditioning of -0.5 V applied to OMD for 100 s (1000 sweeps of 100 ms) to depress device conductivity.

Supporting Information

Supporting Information is available from the Wiley Online Library or from the author.

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Conflict of Interest

The authors declare no conflict of interest.

Keywords

artificial synapses, conducting and ionic polymers, live neuronal cells, memristive devices, synaptic prosthesis

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- [1] P. Fromherz, A. Offenhausser, T. Vetter, J. Weis, *Science* **1991**, 252, 1290.
- [2] S. Vassanelli, P. Fromherz, *Appl. Phys. A: Mater. Sci. Process.* **1998**, 66, 459.
- [3] D. Kuzum, S. Yu, H. S. Wong, *Nanotechnology* **2013**, 24, 382001.
- [4] C. Rossant, S. N. Kadir, D. F. M. Goodman, J. Schulman, M. L. D. Hunter, A. B. Saleem, A. Grosmark, M. Belluscio, G. H. Denfield, A. S. Ecker, A. S. Tolias, S. Solomon, G. Buzsaki, M. Carandini, K. D. Harris, *Nat. Neurosci.* **2016**, 19, 634.
- [5] G. Bruzsaki, E. Stark, A. Berényi, D. Khodagholy, D. R. Kipke, E. Yoon, K. D. Wise, *Neuron* **2015**, 86, 92.
- [6] L. R. Hochberg, D. Bacher, B. Jarosiewicz, N. Y. Masse, J. D. Simeral, J. Vogel, S. Haddadin, J. Liu, S. S. Cash, P. van der Smagt, J. P. Donoghue, *Nature* **2012**, 485, 372.
- [7] V. Erokhin, T. Berzina, M. P. Fontana, *J. Appl. Phys.* **2005**, 97, 064501.
- [8] E. Kang, K. Neoh, K. Tan, *Prog. Polym. Sci.* **1998**, 23, 277.
- [9] V. Erokhin, T. Berzina, A. Smerieri, P. Camorani, S. Erokhina, M. P. Fontana, *Nano Commun. Networks* **2010**, 1, 108.
- [10] V. Erokhin, M. Fontana, *J. Comput. Theor. Nanosci.* **2011**, 8, 313.
- [11] P. Gkoupidenis, N. Schaefer, X. Strakosas, J. A. Fairfield, G. G. Malliaras, *Appl. Phys. Lett.* **2015**, 107, 263302.
- [12] S. J. Etherington, S. E. Atkinson, G. J. Stuart, S. R. Williams, *Synaptic Integration in eLS*, John Wiley and Sons Ltd., New Jersey, USA **2010**.
- [13] D. Fricker, R. Miles, *Neuron* **2000**, 28, 559.
- [14] G. Buzsáki, A. Draguhn, *Science* **2004**, 304, 1926.
- [15] B. P. Timko, T. Cohen-Karni, Q. Qing, B. Tian, C. M. Lieber, *IEEE Trans. Nanotechnol.* **2010**, 9, 269.
- [16] R. R. Harrison, C. Charles, *IEEE J. Solid-State Circuits* **2003**, 38, 958.
- [17] F. Patolsky, B. P. Timko, G. Yu, Y. Fang, A. B. Greytak, G. Zheng, C. M. Lieber, *Science* **2006**, 313, 1100.
- [18] D. Khodagholy, J. N. Gelinis, T. Thesen, W. Doyle, O. Devinsky, G. G. Malliaras, G. Buzsáki, *Nat. Neurosci.* **2015**, 18, 310.
- [19] D. Khodagholy, T. Doublet, P. Quilichini, M. Gurfinkel, P. Leleux, A. Ghestem, E. Ismailova, T. Hervé, S. Sanaur, C. Bernard, *Nat. Commun.* **2013**, 4, 1575.
- [20] M. C. Peterman, J. Noolandi, M. S. Blumenkranz, H. A. Fishman, *Proc. Natl. Acad. Sci. USA* **2004**, 101, 9951.
- [21] C. M. Rountree, A. Raghunathan, J. B. Troy, L. Saggere, *Microsyst. Nanoeng.* **2017**, 3, 17052.
- [22] M. C. Peterman, N. Z. Mehenti, K. V. Bilbao, C. J. Lee, T. Leng, J. Noolandi, S. F. Bent, M. S. Blumenkranz, H. A. Fishman, *Artif. Organs* **2003**, 27, 975.
- [23] L. Chua, *IEEE Trans. Circuit Theory* **1971**, 18, 507.
- [24] D. B. Strukov, G. S. Snider, D. R. Stewart, R. S. Williams, *Nature* **2008**, 453, 80.
- [25] S. H. Jo, T. Chang, I. Ebong, B. B. Bhadviya, P. Mazumder, W. Lu, *Nano Lett.* **2010**, 10, 1297.
- [26] C. Wang, W. He, Y. Tong, R. Zhao, *Sci. Rep.* **2016**, 6, 22970.
- [27] F. Alibart, E. Zamanidoost, D. B. Strukov, *Nat. Commun.* **2013**, 4, 2072.
- [28] V. Demin, V. Erokhin, A. Emelyanov, S. Battistoni, G. Baldi, S. Iannotta, P. Kashkarov, M. Kovalchuk, *Org. Electron.* **2015**, 25, 16.
- [29] V. Erokhin, T. Berzina, P. Camorani, A. Smerieri, D. Vavoulis, J. Feng, M. P. Fontana, *BioNanoScience* **2011**, 1, 24.
- [30] M. Ziegler, R. Soni, T. Patelczyk, M. Ignatov, T. Bartsch, P. Meuffels, H. Kohlstedt, *Adv. Funct. Mater.* **2012**, 22, 2744.
- [31] I. Gupta, A. Serb, A. Khiat, R. Zeitler, S. Vassanelli, T. Prodromakis, *Nat. Commun.* **2016**, 7, 12805.
- [32] L. J. Juarez-Hernandez, N. Cornella, L. Pasquardini, S. Battistoni, L. Vanzetti, S. Caponi, M. Dalla Serra, S. Iannotta, C. Pederzoli, P. Macchi, C. Musio, *Biophys. Chem.* **2016**, 208, 40.
- [33] R. A. Kaul, N. I. Syed, P. Fromherz, *Phys. Rev. Lett.* **2004**, 92, 038102.
- [34] A. Dimonte, T. Berzina, A. Cifarelli, V. Chiesi, F. Albertini, V. Erokhin, *Phys. Status Solidi C* **2015**, 12, 197.
- [35] A. Romeo, A. A. Dimonte, G. Tarabella, P. D'Angelo, V. Erokhin, S. Iannotta, *APL Mater.* **2015**, 3, 014909.
- [36] A. Dimonte, F. Fermi, T. Berzina, V. Erokhin, *Mater. Sci. Eng., C* **2015**, 53, 11.
- [37] G. Decher, *Science* **1997**, 277, 1232.
- [38] S. Erokhina, V. Sorokin, V. Erokhin, *Electron. Mater. Lett.* **2015**, 11, 801.
- [39] S. Erokhina, V. Sorokin, V. Erokhin, *AIP Adv.* **2015**, 5, 027129.
- [40] F. Pincella, P. Camorani, V. Erokhin, *Appl. Phys. A* **2011**, 104, 1039.
- [41] D. A. Lapkin, A. V. Emelyanov, V. A. Demin, V. V. Erokhin, L. A. Feigin, P. K. Kashkarov, M. V. Kovalchuk, *Appl. Phys. Lett.* **2018**, 112, 043302.
- [42] C. Auner, U. Palfinger, H. Gold, J. Kraxner, A. Haase, T. Haber, M. Sezen, W. Groogger, G. Jakopic, J. R. Krenn, G. Leising, B. Stadlober, *Org. Electron.* **2010**, 11, 552.
- [43] M. V. Bennett, R. S. Zukin, *Neuron* **2004**, 41, 495.
- [44] G. Baldi, S. Battistoni, G. Attolini, M. Bosi, C. Collini, S. Iannotta, L. Lorenzelli, R. Mosca, J. Ponraj, R. Verucchi, *Semicond. Sci. Technol.* **2014**, 29, 104009.
- [45] S. Battistoni, A. Dimonte, V. Erokhin, *Org. Electron.* **2016**, 38, 79.
- [46] V. I. Troitsky, T. S. Berzina, M. P. Fontana, *Mater. Sci. Eng., C* **2002**, 22, 239.
- [47] V. Erokhin, T. Berzina, P. Camorani, M. P. Fontana, *Colloids Surf., A* **2008**, 321, 218.